

## **Amendments to the Claims**

This listing of claims will replace all prior versions, and listings, of claims in the application:

### **Listing of Claims:**

1-35 (canceled)

36. (new): A thin film transistor substrate comprising:

an insulating substrate;

a first signal line including a gate electrode and formed on the insulating substrate;

a second signal line formed on the insulating substrate;

a gate insulating layer covering the first and the second signal lines;

a semiconductor layer formed on the gate insulating layer;

a third signal line interposing the first and the second signal lines;

a drain electrode and a source electrode formed on the semiconductor layer, wherein the third signal line is connected to the drain electrode;

a protective layer having a contact hole exposing the drain electrode, wherein the contact hole is located over the second signal line; and

a pixel electrode connected to the drain electrode through the contact hole.

37. (new): The thin film resistor of claim 36, wherein the pixel electrode overlaps the first and the second signal lines.

38. (new): The thin film resistor of claim 36, wherein the drain electrode is extended over the second signal line.

39. (new): The thin film resistor of claim 36, further comprising a connection portion connected to the second signal line.

40. (new): The thin film resistor of claim 39, wherein the pixel electrode overlaps the connection portion.

41. (new): The thin film resistor of claim 40, wherein the connection portion overlaps the third signal line.